TRANSISTOR-AMPLIFIER 35 M

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The 35 M is a fully transistorized amplifier, free from iron cores and unaffected by supply voltage variations.

Output is 60 W. music power.

Distortion is less than 1% at 20 W. sine output in frequency range of 20 cs to 20 Kcs.

The amplifier has 16 transistors and 12 silicone diodes.

1. PRE-AMPLIFIER

The audio signal from the cartridge is amplified by high input impedance transistor T1 and passed to the base transistor T2. In order to obtain a constant output volume on records with varying recording levels, the next stage acts as AVC amplifier. After being amplified by T2, the audio signal is tapped before C16, and is coupled to the base of T3. The output of T3 in conjunction with D1, D2 and D3 forms a variable internal resistance: If the strength of the incoming signal changes, the AC-impedance of the network will also change and control the signal at the base of T2. Therefore, high signals will be amplified less and low signals will be amplified more. To reduce the background noise of old and worn records, a record noise compensating switch, with 3 positions, has been fitted into the circuit. To reduce the noise of the needle setting down on the record and entering the first groove, the AVC will allow the volume to reach its preset level with an 3 to 4 second delay. The output of each channel can be adjusted over 10 db. with the level controls.

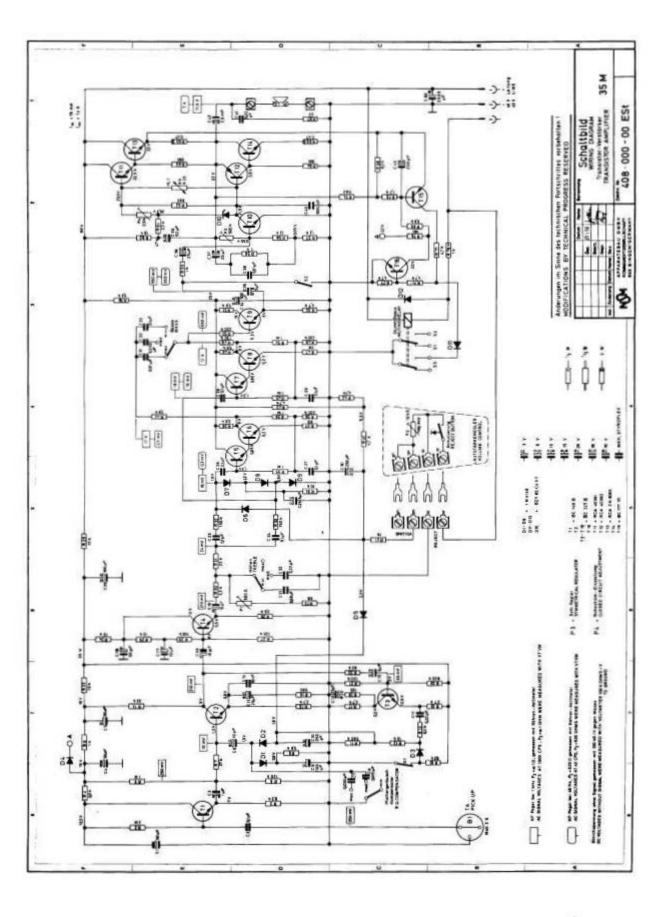
2. VOLUME CONTROL

The signal coming from emitter-follower T4 goes over level control P1 to the volume control circuit. Diodes D6, D7, D8 and D9, and transistors T5, T6, T7 and T8 make up the two wire volume control and bass boast circuit. With full volume, the volume control has zero resistance. No current will flow through the diodes, thus they have a very high resistance, several M ohms. Therefore, the signal going to T5 and T7 is of the same amplitude. T6 and T8 are the drivers for T9. The combination of T5 and T6 drives the bottom end of the bass boost circuit. At full volume, the amplitude and phase of the output of T6 and T8 are the same, so the signal is the same on each end of the bass boost circuit, that means no filtering takes place and the frequency response is flat. As the volume is turned down, current will flow through the diodes, and their resistance decreases. Due to the shunting effect of resistor R34 and capacitor C25, diodes D6 and D7 start reducing the signal before D8 and D9. This means smaller input to T5 and thus smaller output from T6. Since the signal over the bass boost is now different, the higher frequencies will be cut, thus giving the desired bass boost. As the volume control is turned down more, more current will flow through the diodes, D8 and D9 will start to conduct. This in turn will reduce the input to T7 and thus the output of T8, hereby reducing the total volume.

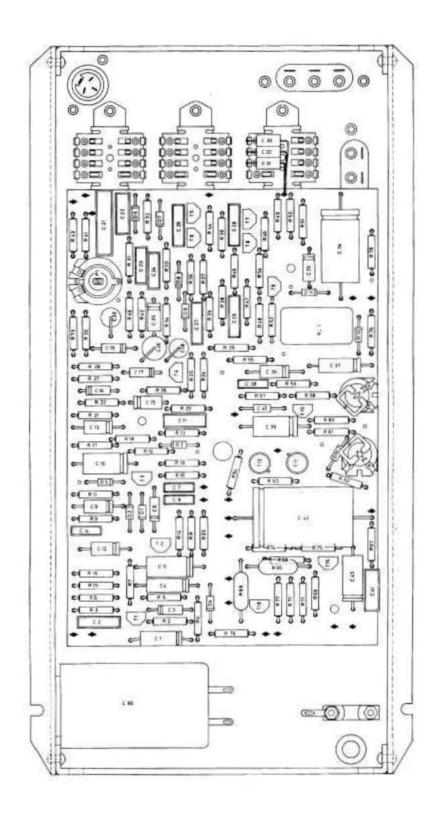
The bass boost will continue throughout the entire volume range, because D6 and D7 will always conduct more current than D8 and D9. Diode D5 is to turn off the AVC, thus achieving complete turn off of the amplifier with minimum volume. T9 is an emitter-follower to match the low impedance of the next stage. With volume control, the volume of both channels can be adjusted together. There are 2 switches each having 3 positions for adjusting the treble and bass.

3. PHASE SPLITTER AND OUTPUT STAGE

The signal from T9 goes over amplifier T10 to the complementary pair phase splitters T11 and T12, these drive the transformerless push-pull output pair T13 and T14. The thermistor HL1 in base of T11 and T12 gives the circuit good thermal stability. Fine control P3 keeps both drivers symmetrical, and P4 adjusts the rest current (nosignal) of the output stage. The overload protection is determined by the emitter current of the output stage. The valtage over R65, created by the emitter current flowing through it, is coupled to T15 over an intergrating network with a time cinstant of 1 sec. When T15 starts conducting, the base of T16 becomes positive, thus placing point A in the plate at ground potential. This point is the valtage supply of the input stage. The audio signal is hereby completely cut-off. When the record rejects, the muting relay is energized. One of the muting contacts will bring the collector of T15 and the base of T16 back to negative, driving these transistors in cut-off, this on condition that the overload is removed from the circuit. In the muted state, the base of T10 is to ground over contacts S2, and the ground line to diode D3 is open over cantacts S1.



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R 2	Carbon resistor		Megohm 1/3			P 1	Trimmer resistor	250 Ohm 1/2 W. lin.
R 3	Carbon resistor	8 200	Ohm 1/3	W. ±	10%	P 3	Adjusting resistor	500 000 Ohm, lin.
R 4	Carbon resistor	3 300	Ohm 1/2 !	W. 3	10%	P 4	Adjusting resistor	2 500 Ohm, lin.
R 5	Carbon resistor		Megohm 1/2			C 1	Lytic	50 Mfd
		120 000		W.		C 2	Mylar	0.1 Mfd
R 6	Carbon resistor					C 3	Lytic	1 Mfd/ 35 V
R 7	Carbon resistor	27 000		W. =		C 4		50 Mfd/ 15 V
R B	Carbon resistor	1 000	The state of the s				Lytic	
R 9	Carbon resistor	3 900	Ohm 1/3 1	W. :	10%	C 5	Lytic	50 Mtd/ 25 V
R10	Carbon resistor	82 000	Ohm 1/4 1	W. :	10%	C 6	Lytic	10 Mfd
R11	Carbon resistor	390 000	Ohm 1/2 1	W.	10%e	C 7	Mylar	0.033 Mtd
R12	Carbon resistor	10 000			+ 10%	C 8	Mylar	0.015 Mtd 400 V
		8 200			10%	C 9	Lytic	100 Mfd/ 3 V
R13	Carbon resistor					C10	Lytic	250 Mfd/ 6 V
R14	Carbon resistor	22 000		7.75	+ 10%	100	E-1000	
R15	Carbon resistor	2 700		170	± 10° s	C11	Mylar	0.22 Mfd
R16	Carbon resistor	560	Ohm 1/3 1		+ 10%	C12	Lytic	25 Mtd/ 10 V
R17	Carbon resistor	4 700	Ohm 1/s 1	W. :	+ 10%	C13	Lytic	25 Mfd/ 10 V
R18	Carbon resistor	120	Ohm 1/2 1	N	+ 10%	C14	Mylar	0.01 Mfd
R19	Carbon resistor	27 000	Ohm 1/2 1		10%	C15	Lytic	5 Mfd/ 35 V
R20	Carbon resistor	820 000	Ohm 1/2 1		+ 10%	C16	Lytic	10 Mfd/ 25 V
						C17	Lytic	10 Mtd/ 25 V
R21	Carbon resistor	120 000	Ohm 1/s 1		+ 10%			50 Mfd/ 25 V
R22	Carbon resistor	82 000			± 10%	C18	Lytic	
R23	Carbon resistor	10 000	Ohm 1/4 V	N. :	10%	C19	Lytic	10 Mtd/ 25 V
R24	Carbon resistor	10.000	Ohm 1/3 1	N	10%	C20	Lytic	100 Mfd/ 35 V
R25	Carbon resistor	10 000	Ohm 1/a V	N.	10%	C21	Mylar	0.68 Mfd
R26	Carbon resistor	100 000			10%	C22	Mylar	0.22 Mfd
R27	Carbon resistor	120 000			10%	C23	Mylar	0.1 Mfd
						C24	Mylar	0.1 Mfd
H28	Carbon resistor	3 900			10%			5 Mfd/ 35 V
R29	Carbon resistor	10 000	Ohm 1/3 1			C25	Lytic	
R30	Carbon resistor	2 200	Ohm 1/3 1	W. :	10%	C26	Mylar	0.1 Mfd
R31	Carbon resistor	22 000	Ohm 1/2 1	N. 3	10%	C27	Mylar	0.1 Mfd
R32	Carbon resistor	150 000	Ohm 1/2 1	N.	10%	C28	Mylar	0.1 MId
R33	Carbon resistor	150 000			± 10%	C29	Mylar	0.1 Mfd
R34	Carbon resistor	10 000			10%	C30	Lytic	250 Mtd/ 6 V
						C31	Mylar	0.01 Mfd
R35	Carbon resistor		Megohm 1/3 1		10%			0.033 Mtd
R36	Carbon resistor	5 600				C32	Mylar	
R37	Carbon resistor	68	Ohm Vs V		± 10%	C33	Mylar	0.1 Mfd
R38	Carbon resistor	1	Megohm 1/2 V	N. :	10%	C34	Lytic	500 Mfd
R39	Carbon resistor	220 000	Ohm 1/3 1	N ·	10%	C35	Lytic	5 Mtd/ 35 V
B40	Carbon resistor	4 700	- March 1997		+ 10%	C36	Lytic	25 Mfd/ 10 V
R41	Carbon resistor		Ohm 1/a l		+ 10%	C37	Lytic	25 Mfd/ 35 V
		200				C38	Mylar	0.01 Mfd
R42	Carbon resistor	4 700	Ohm 1/3 1	27/1 - 7	± 10%			50 Mfd/ 35 V
R43	Carbon resistor	4 700	Ohm 1/2 1		+ 10%	C39	Lytic	
R44	Carbon resistor	3 900	Ohm 1/2 1	N. :	10%	C40	Mylar	0.001 Mfd / 160 V
R45	Carbon resistor	1	Megohm 1/3 V		+ 10%	C41	Mylar	0.22 Mtd
R46	Carbon resistor	5 600	Ohm 1/2 V	N.	+ 10%	C42	Lytic	2500 Mtd/ 35 V
R47	Carbon resistor	68	Ohm 1/2 1	17.7	+ 10%	C43	Lytic	250 Mfd/ 6 V
R48	Carbon resistor	220 000	Ohm 1/2 1		+ 10%	C80	Lytic	2500 Mfd/ 70 V
R49					± 10%	D 1	Silicon diode	1 N 4148
	Carbon resistor	150 000	The state of the s					1 N 4148
R50	Carbon resistor	220 000			± 10°/a	D 2	Silicon diode	
R51	Carbon resistor	5 600			± 10%	D 3	Silicon diode	1 N 4148
R52	Carbon resistor	4 700			+ 10%	D 4	Silicon diade	1 N 4148
R54	Carbon resistor	1	Megohm 1/2 V	N	+ 10%	D 5	Silicon diade	1 N 4148
R55	Carbon resistor	1 000	Ohm 1/2 V	N.	+ 10%	D 6	Silicon diade	1 N 4148
R56	Carbon resistor	1 000		N -	+ 10%	D 7	Silicon diede	1 N 4148
R57	Carbon resistor	1 200			+ 10%	D 8	Silicon diode	1 N 4148
R58	Carbon resistor	12 000			10%	D 9	Silicon diode	1 N 4148
R60	Charles to the second s	4 000	M4	4.4	10 10 10 10 10 10 10 10 10 10 10 10 10 1	010		BZY 85 C 4 V 7
	Carbon resistor	1 800			± 10%		Zener diode	
R61	Carbon resistor	2 700			± 10%	D11	Silican diode	1 N 4148
R62	Carbon resistor	560	Ohm 1/a V		± 10°/0	D12	Silicon diode	1 N 4148
R63	Carbon resistor	330	Ohm 1/2 V	N	+ 10%	T 1	Transistor	BC 149 B
R64	Carbon resistor	330	Ohm 1/x V	N	+ 10%	T 2	Transistor	BC 149 B
R65	Wire resistor		Ohm 21	N	+ 10%	T 3	Transistor	BC 147 B
R6E	Wire resistor		Ohm 21	11	+ 10%	T 4	Transistor	BC 147 B
R67	Carbon resistor					T 5	Transistor	BC 147 B
			Ohm 1/2 V					
R68	Carbon resistor	8 200	1022 CO 10		± 5%.	T 6	Transistor	BC 147 B
R69	Carbon resistor	5 600			± 5%	T 7	Transistor	BC 147 B
B71/R71	Carbon resistor	4 700	Ohm 1/2 V	N. :	± 5%	T 8	Transistor	BC 147 B
R73	Carbon resistor		Ohm 1/2 V		± 10%	T 9	Transistor	BC 147 B
R74	Carbon resistor	1 000		CCD -	+ 5%	T10	Transistor	BC 147 B
R75	Carbon resistor	1 200			± 5%	T11	Transistor	40361 RCA
R76						T12	Transistor	40362 RCA
	Carbon resistor	1 000			± 10%	T13	Transistor	2N 30 55 RCA
R77	Carbon resistor	4 700			± 5%			2N 3055 RCA
R78	Carbon resistor	3 300	Ohm 1/2 V	N.	± 10%	T14	Transistor	
R79	Carbon resistor	180	Ohm 1/a V	N.	± 5%	T15	Transistor	BC 177 VI/BC 157 A
		111000000000000000000000000000000000000	Carlon			T16	Transistor	BC 147 B
RL 1	Mute relay	V 23154	NO 721 -					
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